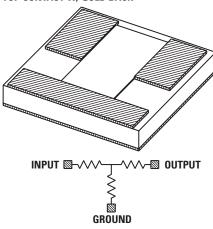
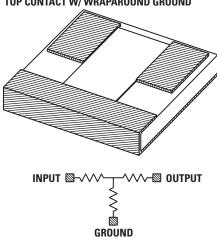
ATTENUATOR

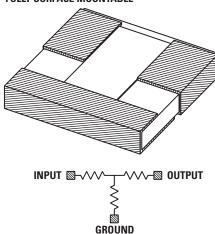
MSAT-21 TOP CONTACT W/ GOLD BACK



MSAT-22 TOP CONTACT W/ WRAPAROUND GROUND



MSAT-23
FULLY SURFACE MOUNTABLE





THIN FILM DIVISION 20 DAVID ROAD, N. ATTLEBORO, MA 02760 508-695-0203 FAX: 508-695-6076 POWER THIN FILM ATTENUATORS

MSAT-21, MSAT-22, MSAT-23 SERIES

The MSAT series Thin Film Power chip attenuators provide attenuation accuracy for frequencies through 20 GHz. They offer the low noise, stray capacitance and tight tolerance of Thin Film in compact sizes that make them ideal for smaller microwave and stripline applications at operating powers to 250mW.

MECHANICAL DATA

SIZE 0.077" x 0.061" (±0.003") 0.015" (±0.003") THICK SUBSTRATE 99.6% ALUMINA

BOND PADS 25K Å MIN. GOLD; WIRE OR RIBBON BONDABLE, OR SOLDERABLE.

BACKSIDE SURFACE GOLD

RESISTOR MATERIAL TANTALUM NITRIDE

ELECTRICAL DATA

ATTENUATION RANGE
ATTENUATION ACCURACY
FREQUENCY RANGE

-1dB THROUGH -24dB; (0.5dB STEPS AVAILABLE)
±0.2dB
DC THROUGH 20 GHz

IMPEDANCE 50Ω VSWR 1.5:1 MAX.

COMMON SERIES DATA

OPERATING TEMP RANGE

STRAY DISTRIBUTED

CAPACITANCE

CURRENT NOISE -20dB TYPICAL
POWER RATING 250mW, (70°C DERA

POWER RATING 250mW, (70°C DERATED LINEARLY TO 150°C) $P = E^2/R$ T.C.R. $\pm 150ppm/^{\circ}C$

HIGH TEMP EXPOSURE 150°C, 100 HRS., ±0.25% MAX. ΔR/R: ±0.03% MSI TYPICAL THERMAL SHOCK MIL-STD 202, METHOD 107F, ±0.25% MAX. ΔR/R: ±0.1% N

THERMAL SHOCK MIL-STD 202, METHOD 107F, ±0.25% MAX. ΔR/R: ±0.1% MSI TYPICAL STABILITY 1000 HRS., 70°C, 100% POWER, ±0.5% MAX. ΔR/R: ±0.1% MSI TYPICAL

-55°C TO +150°C

ALUMINA 0.06pF

PART NUMBER DESIGNATION

MSAT	_	XG	_	dB
SERIES		21		03
		22		
		23		

EXAMPLE: MSAT 23G-03dB (MSAT 23 Series: -3dB)